## **PF0414B**

# MOS FET Power Amplifier Module for DCS 1800 Handy Phone

## **HITACHI**

ADE-208-432C (Z) 4th Edition December 1997

### **Application**

For DCS 1800 class1 1710 to 1785 MHz.

#### **Features**

• 3stage amplifier: 0 dBm input

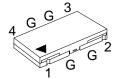
• Lead less thin & small package: 2 mm Max & 0.2cc

High efficiency: 40% Typ at 32.5 dBmWide gain control range: 70 dB Typ

• Low voltage operation: 3.5 V

## **Pin Arrangement**

• RF-K



1: Pin

2: vapo 3: Vdd

4: Pout G: GND

### **Absolute Maximum Ratings** (Tc = 25°C)

Item	Symbol	Rating	Unit	
Supply voltage	$V_{DD}$	8	V	
Supply current	I <sub>DD</sub>	2	А	
V <sub>APC</sub> voltage	$V_{APC}$	4	V	
Input power	Pin	10	mW	
Operating case temperature	Tc (op)	-30 to +100	°C	
Storage temperature	Tstg	-30 to +100	°C	
Output power	Pout	3	W	

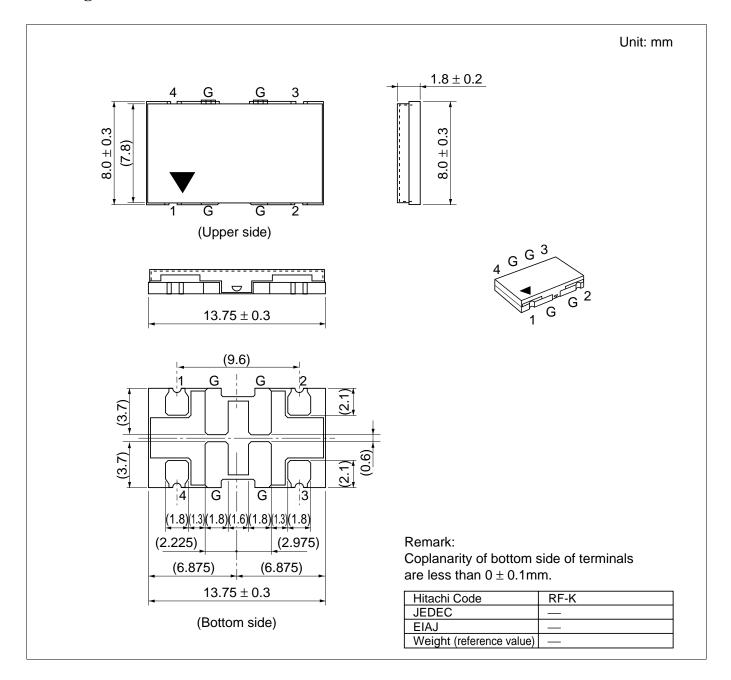


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## **Electrical Characteristics** ( $Tc = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Frequency range	f	1710	_	1785	MHz	
Control voltage range	$V_{APC}$	0.5	_	2.2	V	
Drain cutoff current	I <sub>DS</sub>	_	_	100	μΑ	$V_{DD} = 8 \text{ V}, V_{APC} = 0 \text{ V}$
Total efficiency	$\eta_{\scriptscriptstyle T}$	35	40	_	%	$Pin = 0 dBm, V_{DD} = 3.5 V,$
2nd harmonic distortion	2nd H.D.	_	<b>–45</b>	-35	dBc	Pout = 32.5 dBm (at APC controlled),
3rd harmonic distortion	3rd H.D.	_	<b>–</b> 45	-35	dBc	$R_L = Rg = 50 \ \Omega, Tc = 25^{\circ}C$
Input VSWR	VSWR (in)	_	1.5	3	_	_
Output power (1)	Pout (1)	32.5	33.0	_	dBm	Pin = 0 dBm, $V_{DD}$ = 3.5 V, $V_{APC}$ = 2.2 V, $R_{L}$ = $Rg$ = 50 Ω, Tc = 25°C
Output power (2)	Pout (2)	31	31.5		dBm	Pin = 0 dBm, $V_{DD}$ = 3.0 V, $V_{APC}$ = 2.2 V, $R_{L}$ = $Rg$ = 50 Ω, Tc = 85°C
Isolation	_	_	-36	-33	dBm	Pin = 0 dBm, $V_{DD}$ = 3.5 V, $V_{APC}$ = 0.5 V, $R_{L}$ = $Rg$ = 50 Ω, Tc = 25°C
Switching time	tr, tf	_	1	2	μs	Pin = 0 dBm, $V_{DD}$ = 3.5 V, Pout = 32.5 dBm, $R_L$ = Rg = 50 $\Omega$ , Tc = 25°C
Stability	_	No par oscilla			_	Pin = 0 dBm, $V_{DD}$ = 3 to 5.1 V, Pout $\leq$ 32.5 dBm (at APC controlled), Rg = 50 $\Omega$ , t = 20 sec., Tc = 25°C, Output VSWR = 6 : 1 All phases

## **Package Dimensions**



### **Cautions**

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